

V <sub>CES</sub>	650V
I <sub>C(100°C)</sub>	30A
V <sub>CE(sat) (Typ.)</sub>	1.5V
P <sub>D</sub>	194W

#### Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching & Low Switching Loss
- 3) Short Circuit Withstand Time 2µs
- 4) Pb free Lead Plating ; RoHS Compliant

#### Applications

Solar Inverter

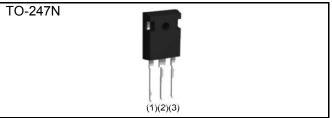
UPS

Welding

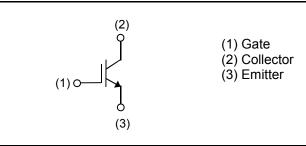
IH

PFC

#### Outline



#### Inner Circuit



#### Packaging Specifications

Туре	Packaging	Tube
	Reel Size (mm)	-
	Tape Width (mm)	-
	Basic Ordering Unit (pcs)	450
	Packing Code	C11
	Marking	RGTV60TS65

#### •Absolute Maximum Ratings (at T<sub>C</sub> = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V <sub>CES</sub>	650	V
Gate - Emitter Voltage		V <sub>GES</sub>	±30	V
Collector Current	$T_{\rm C}$ = 25°C	۱ <sub>C</sub>	60	A
	T <sub>C</sub> = 100°C	Ι <sub>C</sub>	30	A
Pulsed Collector Current		I <sub>CP</sub> <sup>*1</sup>	120	A
Power Dissinction	$T_{\rm C}$ = 25°C	P <sub>D</sub>	194	W
Power Dissipation	T <sub>C</sub> = 100°C	P <sub>D</sub>	97	W
Operating Junction Temperature		Tj	-40 to +175	°C
Storage Temperature		T <sub>stg</sub>	–55 to +175	°C

\*1 Pulse width limited by T<sub>imax.</sub>

#### Thermal Resistance

Parameter	Symbol	Values			Unit
Parameter		Min.	Тур.	Max.	Onit
Thermal Resistance IGBT Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	0.77	°C/W

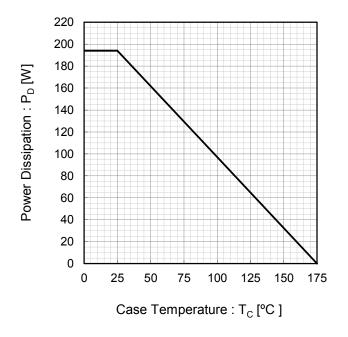
## ●IGBT Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit	
Faranielei	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Collector - Emitter Breakdown Voltage	BV <sub>CES</sub>	I <sub>C</sub> = 10μΑ, V <sub>GE</sub> = 0V	650	-	-	V	
Collector Cut - off Current	I <sub>CES</sub>	V <sub>CE</sub> = 650V, V <sub>GE</sub> = 0V	-	-	10	μA	
Gate - Emitter Leakage Current	I <sub>GES</sub>	V <sub>GE</sub> = ±30V, V <sub>CE</sub> = 0V	-	-	±200	nA	
Gate - Emitter Threshold Voltage	V <sub>GE(th)</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 21.0mA	5.0	6.0	7.0	V	
Collector - Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = 30A, V <sub>GE</sub> = 15V T <sub>j</sub> = 25°C T <sub>j</sub> = 175°C	-	1.5 1.85	1.9 -	V	

# •IGBT Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

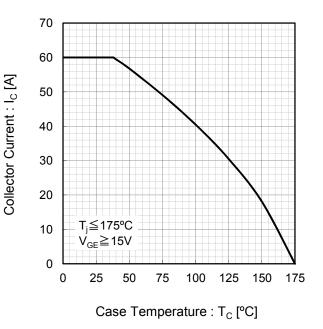
Deremeter	Symbol	Conditions	Values			1.1
Parameter	Farameter Symbol Conditions		Min.	Тур.	Max.	Unit
Input Capacitance	C <sub>ies</sub>	V <sub>CE</sub> = 30V	-	1730	-	
Output Capacitance	C <sub>oes</sub>	V <sub>GE</sub> = 0V	-	74	-	pF
Reverse Transfer Capacitance	C <sub>res</sub>	f = 1MHz	-	30	-	
Total Gate Charge	$Q_g$	V <sub>CE</sub> = 400V	-	64	-	
Gate - Emitter Charge	$Q_{ge}$	I <sub>C</sub> = 30A	-	14	-	nC
Gate - Collector Charge	$Q_{gc}$	V <sub>GE</sub> = 15V	-	24	-	
Turn - on Delay Time	t <sub>d(on)</sub>	I <sub>C</sub> = 30A, V <sub>CC</sub> = 400V	-	33	-	
Rise Time	t <sub>r</sub>	$V_{GE}$ = 15V, $R_{G}$ = 10 $\Omega$	-	12	-	20
Turn - off Delay Time	$t_{d(off)}$	T <sub>j</sub> = 25°C	-	105	-	ns
Fall Time	t <sub>f</sub>	Inductive Load	-	40	-	
Turn - on Switching Loss	$E_{on}$	*E <sub>on</sub> includes diode	-	0.57	-	
Turn - off Switching Loss	$E_{off}$	reverse recovery	-	0.50	-	mJ
Turn - on Delay Time	t <sub>d(on)</sub>	I <sub>C</sub> = 30A, V <sub>CC</sub> = 400V	-	32	-	
Rise Time	t <sub>r</sub>	$V_{GE}$ = 15V, $R_G$ = 10 $\Omega$	-	13	-	20
Turn - off Delay Time	$t_{d(off)}$	T <sub>j</sub> = 175°C	-	121	-	ns
Fall Time	t <sub>f</sub>	Inductive Load	-	80	-	
Turn - on Switching Loss	Eon	*E <sub>on</sub> includes diode	-	0.63	-	
Turn - off Switching Loss	$E_{off}$	reverse recovery	-	0.72	-	mJ
		I <sub>C</sub> = 120A, V <sub>CC</sub> = 520V				
Reverse Bias Safe Operating Area	RBSOA	V <sub>P</sub> = 650V, V <sub>GE</sub> = 15V	FU	LL SQUA	RE	-
		R <sub>G</sub> = 100Ω, T <sub>j</sub> = 175°C				
		$V_{CC} \leq 360V$				
Short Circuit Withstand Time	t <sub>sc</sub>	V <sub>GE</sub> = 15V	2	-	-	μs
		T <sub>j</sub> = 25°C				

#### •Electrical Characteristic Curves



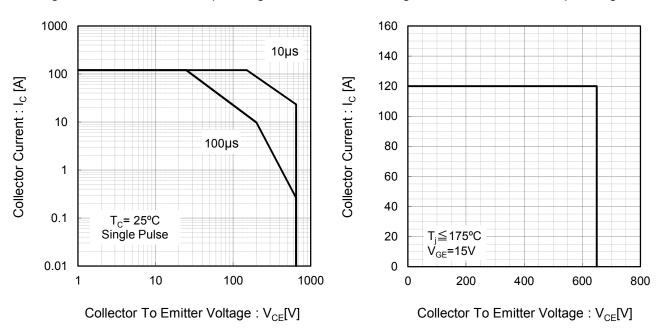
#### Fig.1 Power Dissipation vs. Case Temperature

#### Fig.2 Collector Current vs. Case Temperature

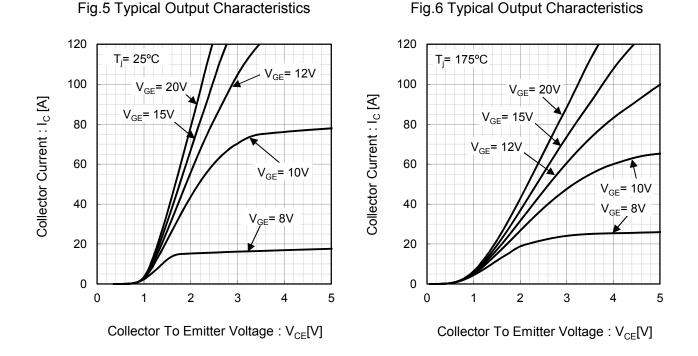


#### Fig.3 Forward Bias Safe Operating Area

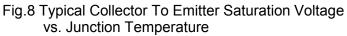
#### Fig.4 Reverse Bias Safe Operating Area

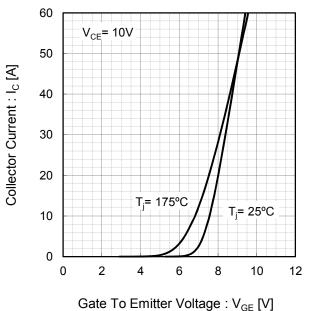


#### Electrical Characteristic Curves

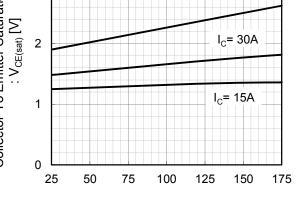


### Fig.7 Typical Transfer Characteristics





4 V<sub>GE</sub>= 15V Collector To Emitter Saturation Voltage 3 I<sub>C</sub>= 60A



Junction Temperature : T<sub>i</sub> [°C]

Fig.10 Typical Collector To Emitter Saturation Voltage

#### •Electrical Characteristic Curves

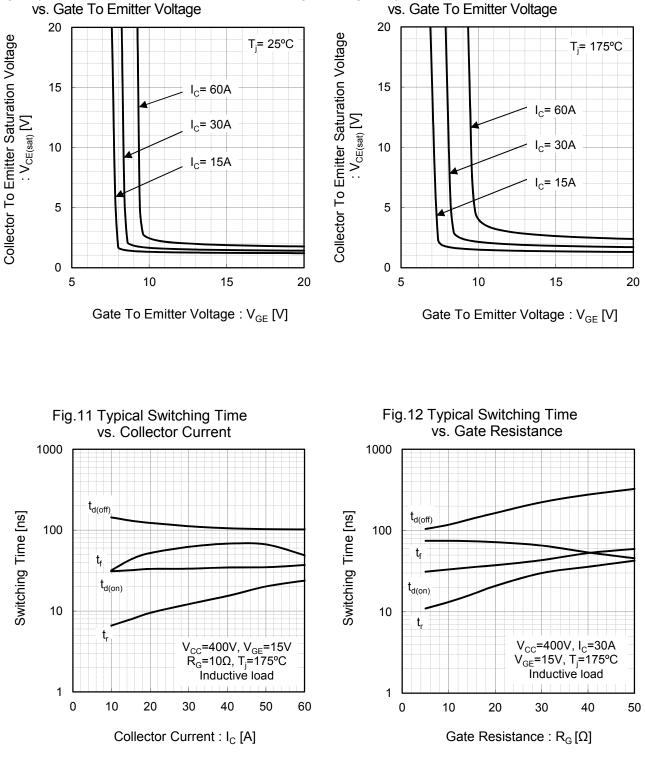
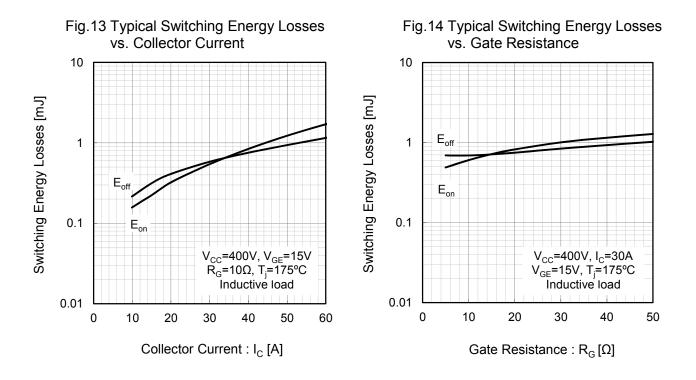


Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage

#### •Electrical Characteristic Curves



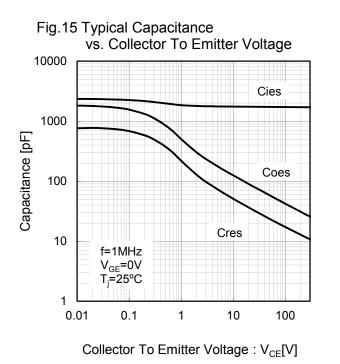
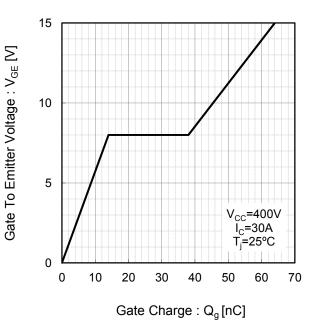


Fig.16 Typical Gate Charge



#### •Electrical Characteristic Curves

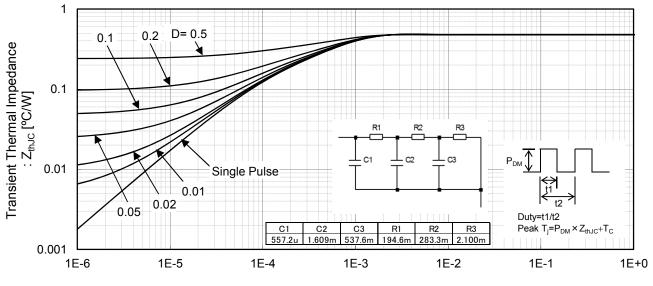
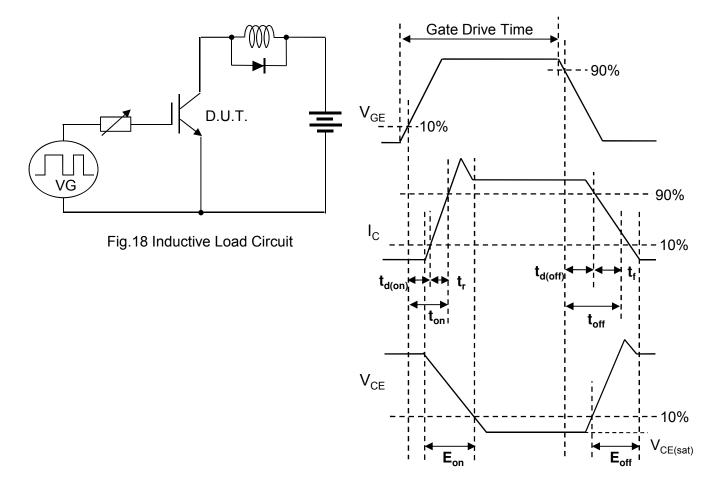


Fig.17 Typical IGBT Transient Thermal Impedance

Pulse Width : t1[s]

#### ●Inductive Load Switching Circuit and Waveform





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